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ON Semiconductor®

FDY100PZ

Single P-Channel (– 2.5V) Specified PowerTrench[®] MOSFET

General Description

Features

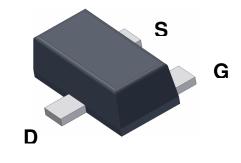
This Single P-Channel MOSFET has been designed using ON Semiconductor's advanced Power Trench process to optimize the $R_{\text{DS(ON)}}$ @ V_{GS} = - 2.5v.

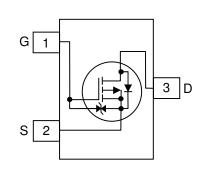
Applications

• Li-Ion Battery Pack



- ESD protection diode (note 3)
- RoHS Compliant





• $-350 \text{ mA}, -20 \text{ V} \text{ R}_{\text{DS(ON)}} = 1.2 \ \Omega \ @ \text{V}_{\text{GS}} = -4.5 \text{ V}$

 $R_{\text{DS(ON)}} = 1.6 \ \Omega \ @ \ V_{\text{GS}} = - \ 2.5 \ V$

Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Unit s
V _{DSS}	Drain-Source Voltage		- 20	V
V _{GSS}	Gate-Source Voltage		± 8	V
ID	Drain Current – Continuous	(Note 1a)	- 350	mA
	– Pulsed		- 1000	
PD	Power Dissipation (Steady State)	(Note 1a)	625	mW
		(Note 1b)	446	
T _J , T _{STG}	Operating and Storage Junction Temp Range	perature	-55 to +150	°C

Thermal Characteristics

R _{eJA}	Thermal Resistance, Junction-to-Ambient (Note 1a)	200	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient (Note 1b)	280	

Package Marking and Ordering Information

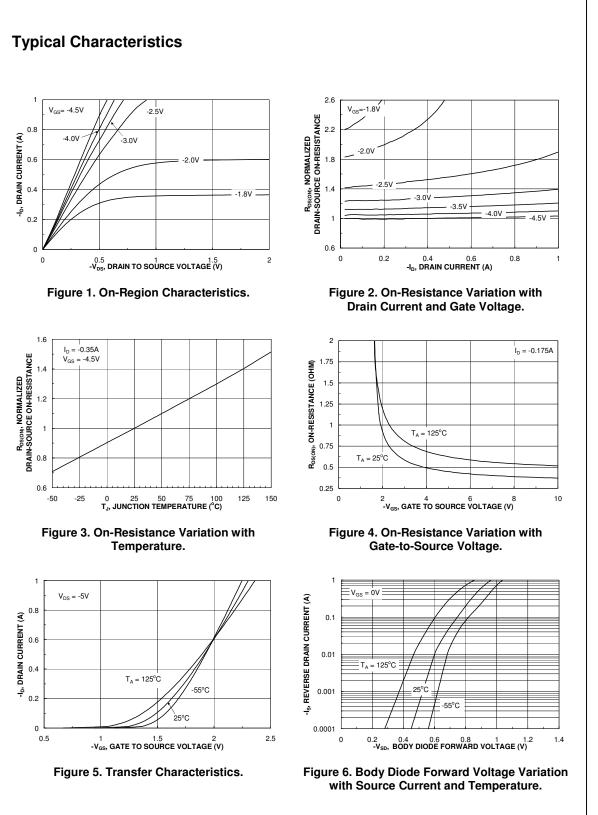
Device Marking	Device	Reel Size	Tape width	Quantity
 А	FDY100PZ	7"	8mm	3000 units

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Publication Order Number: FDY100PZ/D

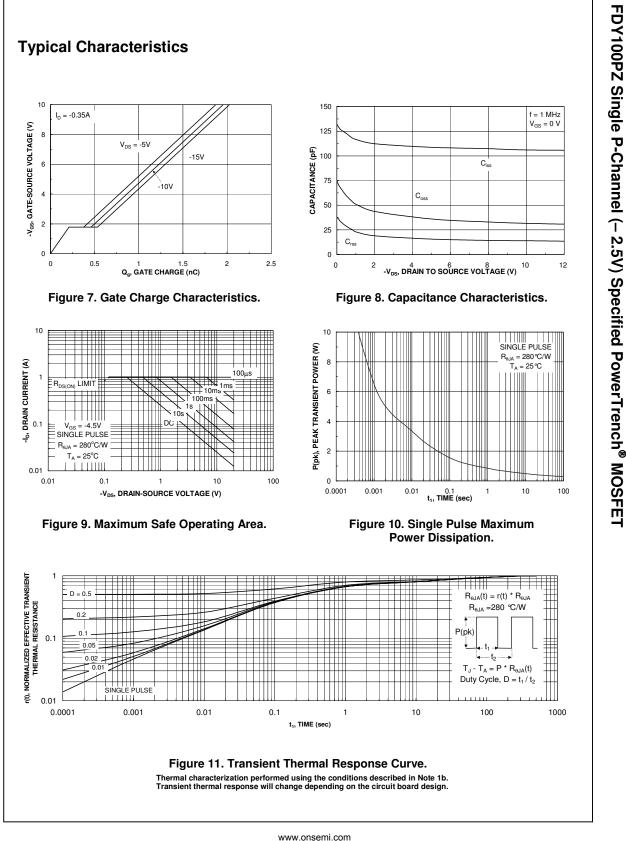
<u></u>	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = -250 \mu A$	- 20			V
<u>ΔBV_{DSS}</u> ΔT,I	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		15		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -16 V$, $V_{GS} = 0 V$			- 3	μA
I _{GSS}	Gate-Body Leakage,	$V_{\text{GS}} = \pm 8 \text{ V}, \qquad V_{\text{DS}} = 0 \text{ V}$			± 10	μA
On Chara	Acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	- 0.65	-1.0	- 1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		-3		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS}=-4.5 \ V, \ I_{D}=-350 \ mA \\ V_{GS}=-2.5 \ V, \ I_{D}=-300 \ mA \\ V_{GS}=-1.8 \ V, \ I_{D}=-150 \ mA \\ V_{GS}=-4.5 \ V, \ I_{D}=-350 \ mA, \\ T_{J}=125^{\circ}C \end{array} $		0.5 0.8 1.3 0.7	1.2 1.6 2.7 1.6	Ω
g _{FS}	Forward Transconductance	$V_{DS} = -5 V$, $I_D = -350 mA$		1		S
Dvnamic	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = -10 V$, $V_{GS} = 0 V$,		100		pF
	Output Capacitance	f = 1.0 MHz		30		pF
Crss	Reverse Transfer Capacitance			15		pF
	· · ·				l	P.
	g Characteristics (Note 2)			C	10	20
t _{d(on)}	Turn-On Delay Time	$V_{DD} = -10 \text{ V}, I_D = -0.5 \text{ A}, V_{GS} = -4.5 \text{ V}, R_{GEN} = 6 \Omega$		6	12	ns
t _r	Turn–On Rise Time			13	23	ns
t _{d(off)}	Turn-Off Delay Time			8	16	ns
t _f	Turn–Off Fall Time			1	2	ns
Q _g	Total Gate Charge	$V_{DS} = -10 \text{ V}, I_D = -350 \text{ mA},$ $V_{GS} = -4.5 \text{ V}$		1.0	1.4	nC
Q _{gs}	Gate–Source Charge	$v_{GS} = -4.3 v$		0.2		nC
Q _{gd}	Gate-Drain Charge			0.3		nC
Drain–So	urce Diode Characteristics	and Maximum Ratings				
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_{S} = -150 m A$ (Note 2)		-0.8	- 1.2	V
	Diode Reverse Recovery Time	$I_F = -350 \text{ mA},$		11		ns
t _{rr}		$dI_F/dt = 100 \text{ A/}\mu\text{s}$				

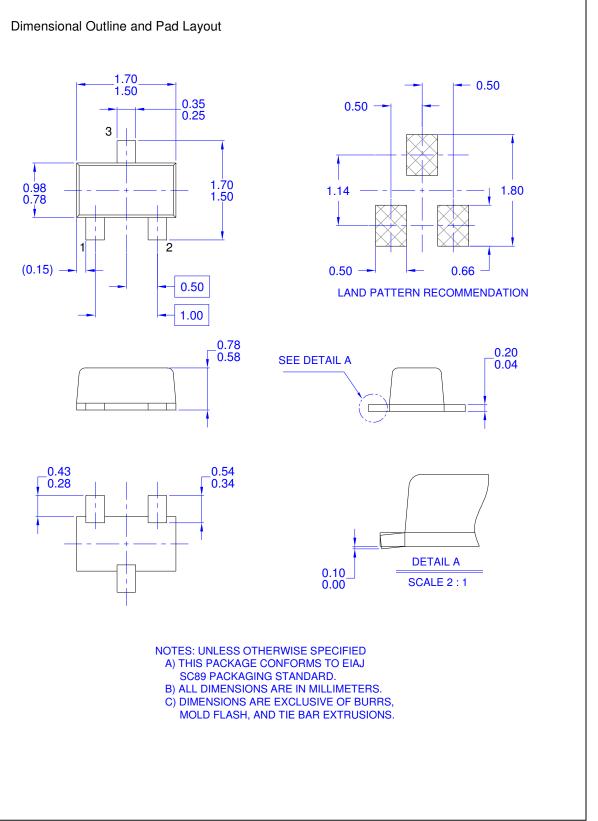
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